

Features

- BV_{CEO} > 40V
- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMDT2907A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

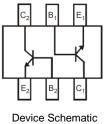
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (Approximate)



SOT363

Top View



Device Schemati Top View

Ordering Information (Note 4)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMDT2222A-7-F	Active	AEC-Q101	K1P	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

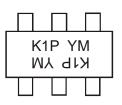
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT363



K1P = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2013		2014	2015		2016	2017		2018	2019		2020
Code	A		В	С		D	E		F	G		Н
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Continuous Collector Current	lc	600	mA

Thermal Characteristics

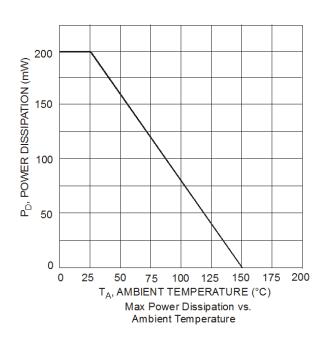
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes: 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristic and Derating Information





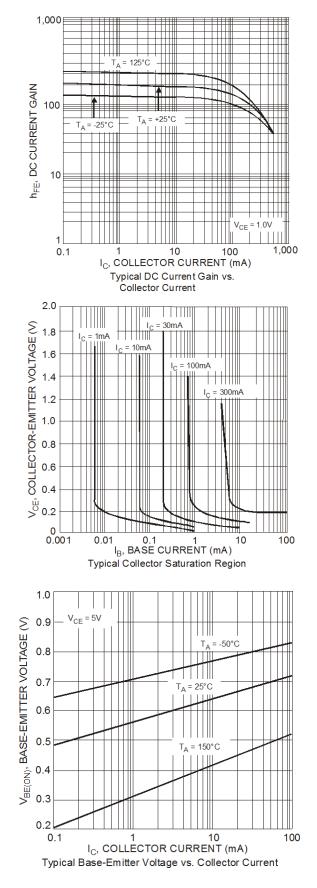
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

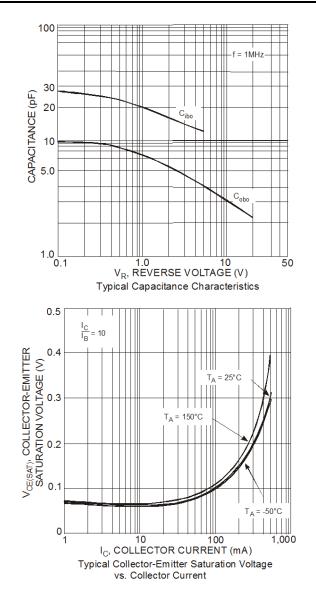
Characteristic	Symbol	Min	Мах	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV _{CBO}	75	_	V	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	40		V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0		V	$I_{E} = 100 \mu A, I_{C} = 0$
Collector-Base Cut-Off Current	I _{CBO}	_	10	nA μA	V _{CB} = 60V, I _E = 0 V _{CB} = 60V, I _E = 0, T _A = +150°C
Collector Cut-Off Current	ICEX		10	nA	$V_{CE} = 60V, V_{BE(OFF)} = 3.0V$
Emitter-Base Cut-Off Current	I _{EBO}	_	10	nA	$V_{\rm EB} = 3V, I_{\rm C} = 0$
Base Cutoff Current	I _{BL}	_	20	nA	$V_{CE} = 60V, V_{BE(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 7)			1		
DC Current Gain	h _{FE}	35 50 75 100 40 50 35	 300 	_	$\begin{split} I_{C} &= 100\mu\text{A}, \ V_{CE} &= 10\text{V} \\ I_{C} &= 1.0\text{mA}, \ V_{CE} &= 10\text{V} \\ I_{C} &= 10\text{mA}, \ V_{CE} &= 10\text{V} \\ I_{C} &= 150\text{mA}, \ V_{CE} &= 10\text{V} \\ I_{C} &= 500\text{mA}, \ V_{CE} &= 10\text{V} \\ I_{C} &= 10\text{mA}, \ V_{CE} &= 10\text{V}, \ T_{A} &= -55^{\circ}\text{C} \\ I_{C} &= 150\text{mA}, \ V_{CE} &= 1.0\text{V} \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.3 1.0	V	$I_{C} = 150$ mA, $I_{B} = 15$ mA $I_{C} = 500$ mA, $I_{B} = 50$ mA
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	0.6	1.2 2.0	V	$\begin{split} I_C &= 150 \text{mA}, \ I_B = 15 \text{mA} \\ I_C &= 500 \text{mA}, \ I_B = 50 \text{mA} \end{split}$
SMALL SIGNAL CHARACTERISTICS	1		1	1	
Output Capacitance	Cobo	—	8.0	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$
Input Capacitance	Cibo	_	25	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Current Gain-Bandwidth Product	f _T	300	—	MHz	$V_{CE} = 20V, I_C = 20mA,$ f = 100MHz
Noise Figure	NF	_	4.0	dB	$V_{CE} = 10V, I_C = 100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS				-	
Delay Time	t _D	—	10	ns	$V_{CC} = 30V, I_{C} = 150mA,$
Rise Time	t _R	_	25	ns	$V_{BE(OFF)} = -0.5V, I_{B1} = 15mA$
Storage Time	ts		225	ns	$V_{CC} = 30V, I_{C} = 150mA,$
Fall Time	tF	—	60	ns	$I_{B1} = I_{B2} = 15 \text{mA}$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

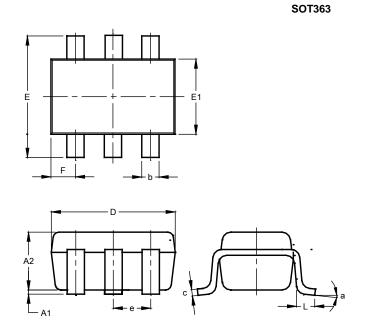






Package Outline Dimensions

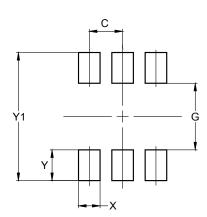
Please see http://www.diodes.com/package-outlines.html for the latest version.



		TOOO						
SOT363								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	1.00					
b	0.10	0.30	0.25					
Ċ	0.10	0.22	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
e	C).650 B	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	Dimen	sions	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500

SOT363



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